





Frequency Tolerance/Stability \_\_\_\_\_\_ ±100ppm Maximum

Operating Temperature Range — -40°C to +85°C

TS -5.000M

- Nominal Frequency 5.000MHz

Pin 1 Connection
Tri-State (High Impedance)

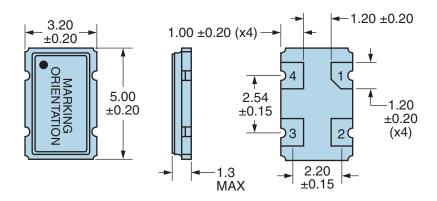
- Duty Cycle 50 ±10(%)

Frequency Tolerance/Stability  ±10 Ope 260  Aging at 25°C  ±5p Operating Temperature Range  40' Supply Voltage  1.8'	.000MHz  100ppm Maximum (Inclusive of all conditions: Calibration Tolerance at 25°C, Frequency Stability over the Operating Temperature Range, Supply Voltage Change, Output Load Change, First Year Aging at 25°, 60°C Reflow, Shock, and Vibration)  5ppm/Year Maximum  10°C to +85°C  .8Vdc ±5%  .5mA Maximum (No Load)
Ope 260           Aging at 25°C         ±5p           Operating Temperature Range         -40°           Supply Voltage         1.8°	Operating Temperature Range, Supply Voltage Change, Output Load Change, First Year Aging at 25°, 60°C Reflow, Shock, and Vibration)  5ppm/Year Maximum  40°C to +85°C  .8Vdc ±5%
Operating Temperature Range -40° Supply Voltage 1.8°	.8Vdc ±5%
Supply Voltage 1.8	.8Vdc ±5%
Inner Command	.5mA Maximum (No Load)
Input Current 3.5i	
Output Voltage Logic High (Voh) 90%	0% of Vdd Minimum (IOH = -8mA)
Output Voltage Logic Low (Vol) 10%	0% of Vdd Maximum (IOL = +8mA)
Rise/Fall Time 6nS	nSec Maximum (Measured at 20% to 80% of waveform)
Duty Cycle 50 :	0 ±10(%) (Measured at 50% of waveform)
Load Drive Capability 15p	5pF Maximum
Output Logic Type CM	MOS
Pin 1 Connection Tri-	ri-State (High Impedance)
,	0% of Vdd Minimum or No Connect to Enable Output, 10% of Vdd Maximum to Disable Output (High npedance)
Standby Current 10µ	0μA Maximum (Pin 1 = Ground)
Absolute Clock Jitter ±10	100pSec Maximum
Start Up Time 10n	0mSec Maximum
Storage Temperature Range -55	55°C to +125°C

ENVIRONMENTAL & MECHANICAL SPECIFICATIONS		
ESD Susceptibility	MIL-STD-883, Method 3015, Class 1, HBM: 1500V	
Fine Leak Test	MIL-STD-883, Method 1014, Condition A	
Flammability	UL94-V0	
Gross Leak Test	MIL-STD-883, Method 1014, Condition C	
Mechanical Shock	MIL-STD-883, Method 2002, Condition B	
Moisture Resistance	MIL-STD-883, Method 1004	
Moisture Sensitivity	J-STD-020, MSL 1	
Resistance to Soldering Heat	MIL-STD-202, Method 210, Condition K	
Resistance to Solvents	MIL-STD-202, Method 215	
Solderability	MIL-STD-883, Method 2003	
Temperature Cycling	MIL-STD-883, Method 1010, Condition B	
Vibration	MIL-STD-883, Method 2007, Condition A	



### **MECHANICAL DIMENSIONS (all dimensions in millimeters)**

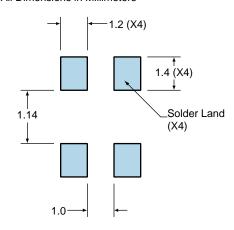


PIN	CONNECTION
1	Tri-State
2	Case Ground
3	Output
4	Supply Voltage

LINE	MARKING
1	EPO
-	XXXXX XXXXX=Ecliptek Manufacturing Identifier

#### **Suggested Solder Pad Layout**

All Dimensions in Millimeters



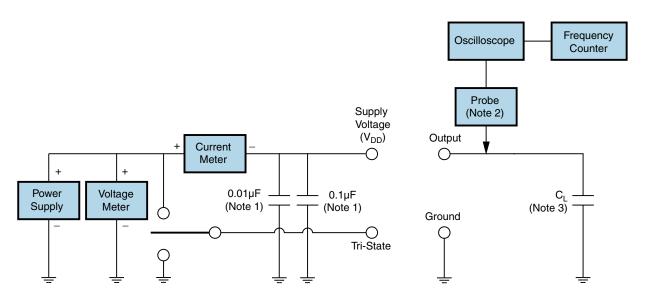
All Tolerances are ±0.1



#### **OUTPUT WAVEFORM & TIMING DIAGRAM**



#### **Test Circuit for CMOS Output**



- Note 1: An external 0.01µF ceramic bypass capacitor in parallel with a 0.1µF high frequency ceramic bypass capacitor close (less than 2mm) to the package ground and supply voltage pin is required.
- Note 2: A low capacitance (<12pF), 10X attenuation factor, high impedance (>10Mohms), and high bandwidth (>300MHz) passive probe is recommended.
- Note 3: Capacitance value C<sub>1</sub> includes sum of all probe and fixture capacitance.



## **Recommended Solder Reflow Methods**



### **High Temperature Infrared/Convection**

T <sub>s</sub> MAX to T <sub>∟</sub> (Ramp-up Rate)	3°C/second Maximum
Preheat	
- Temperature Minimum (T <sub>s</sub> MIN)	150°C
- Temperature Typical (T <sub>s</sub> TYP)	175°C
- Temperature Maximum (T <sub>S</sub> MAX)	200°C
- Time (t <sub>s</sub> MIN)	60 - 180 Seconds
Ramp-up Rate (T <sub>L</sub> to T <sub>P</sub> )	3°C/second Maximum
Time Maintained Above:	
- Temperature (T∟)	217°C
- Time (t∟)	60 - 150 Seconds
Peak Temperature (T <sub>P</sub> )	260°C Maximum for 10 Seconds Maximum
Target Peak Temperature (T <sub>P</sub> Target)	250°C +0/-5°C
Time within 5°C of actual peak (tp)	20 - 40 seconds
Ramp-down Rate	6°C/second Maximum
Time 25°C to Peak Temperature (t)	8 minutes Maximum
Moisture Sensitivity Level	Level 1



## **Recommended Solder Reflow Methods**



### Low Temperature Infrared/Convection 240°C

T <sub>S</sub> MAX to T <sub>L</sub> (Ramp-up Rate)	5°C/second Maximum
Preheat	
- Temperature Minimum (T <sub>s</sub> MIN)	N/A
- Temperature Typical (T <sub>s</sub> TYP)	150°C
- Temperature Maximum (T <sub>s</sub> MAX)	N/A
- Time (t <sub>s</sub> MIN)	60 - 120 Seconds
Ramp-up Rate (T <sub>L</sub> to T <sub>P</sub> )	5°C/second Maximum
Time Maintained Above:	
- Temperature (T∟)	150°C
- Time (t∟)	200 Seconds Maximum
Peak Temperature (T <sub>P</sub> )	240°C Maximum
Target Peak Temperature (T <sub>P</sub> Target)	240°C Maximum 1 Time / 230°C Maximum 2 Times
Time within 5°C of actual peak (t <sub>p</sub> )	10 seconds Maximum 2 Times / 80 seconds Maximum 1 Time
Ramp-down Rate	5°C/second Maximum
Time 25°C to Peak Temperature (t)	N/A
Moisture Sensitivity Level	Level 1

### **Low Temperature Manual Soldering**

185°C Maximum for 10 seconds Maximum, 2 times Maximum.

#### **High Temperature Manual Soldering**

260°C Maximum for 5 seconds Maximum, 2 times Maximum.